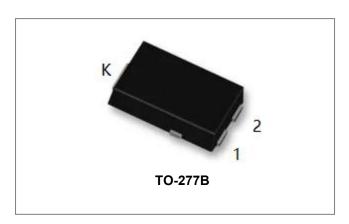






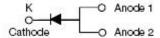
### ST1550S SCHOTTKY RECTIFIER



#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- This is a Halogen Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### **Circuit Diagram**



### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	50	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =80°C, rectangular wave form	15	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	200	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*		@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.38	0.46	
	$V_{F1}$	@ 7.5A, Pulse, T <sub>J</sub> = 25 °C	0.41	0.49	V
		@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.48	0.56	
		@ 5A, Pulse, T <sub>J</sub> = 125 °C	0.26	0.35	
	$V_{F2}$	@ 7.5A, Pulse, T <sub>J</sub> = 125 °C	0.31	0.40	V
		@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.41	0.50	
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25 ^{\circ}\text{C}$	0.14	3	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 125 °C	60	140	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	1100	-	pF

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



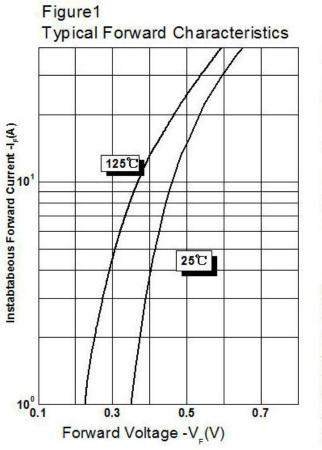


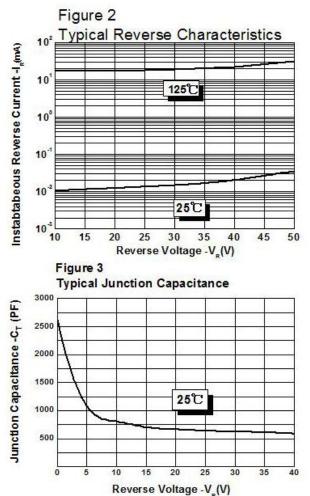


# Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R <sub>0</sub> JC	-	3.5	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$		70	°C/W
Approximate Weight	wt	-	0.08	g

### **Ratings and Characteristics Curves**





<sup>•</sup> China - Germany - Korea - Singapore - United States •

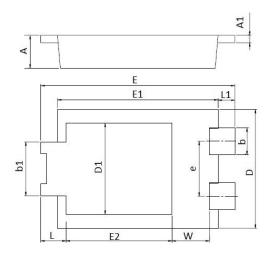
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •

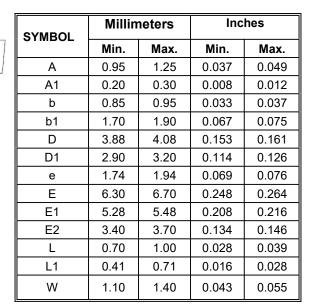




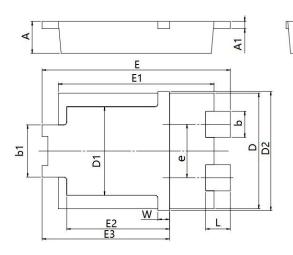


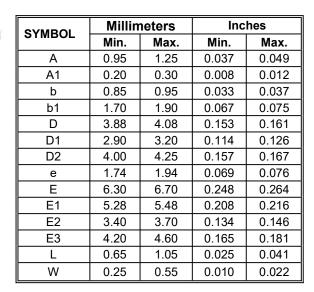
### **Mechanical Dimensions TO-277B**





#### **Mechanical Dimensions TO-277B(New)**





Notes: New Mechanical Dimensions is performed from date code 2236X.

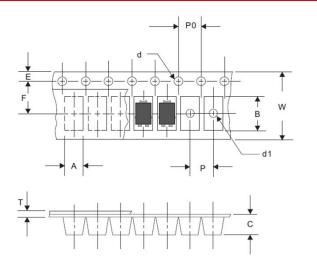
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### **Carrier Tape Specification TO-277B**



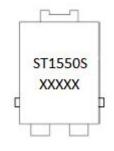
SYMBOL	Millimeters		
	Min.	Max.	
Α	4.28	4.48	
В	6.80	7.10	
С	1.30	1.50	
d	1.40	1.60	
d1	-	1.50	
E	1.65	1.85	
F	5.40	5.60	
Р	7.90	8.10	
P0	3.90	4.10	
Т	0.24	0.44	
W	11.70	12.30	

### Ordering Information

Device	Package	Shipping
ST1550S	TO-277B	5000pcs/ reel
ST1550STR	TO-277B	5000pcs/ reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

### **Marking Diagram**



Where XXXXX is YYWWL

ST = Device Type 15 = Forward Current (15A) 50 = Reverse Voltage (50V)

S = Package type YY = Year WW = Week L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

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